

Influence of Working Pressure on The Magnetic Properties of $\text{Tb}(\text{Fe}_{0.55}\text{Co}_{0.45})_{1.5}$ Thin Films

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In this work the magnetic anisotropies of magnetostriction material $\text{Tb}(\text{Fe}_{0.55}\text{Co}_{0.45})_{1.5}$ (named *a-TerfecoHan*) films were investigated with respect to working pressures in the range 1-7 mTorr. The results obtained show that perpendicular magnetic anisotropy (PMA) can be obtained at a working pressure above 5.1 mTorr. XRD was utilized to clarify the origin of the PMA observed in $\text{Tb}(\text{Fe}_{0.55}\text{Co}_{0.45})_{1.5}$ films, and revealed that all samples were amorphous. Therefore, we propose that the PMA effect is explained by stress produced in film due to internal relaxation process and magnetic anisotropy enhancements caused by magnetoelastic interactions.

Keywords : magnetostriction, perpendicular magnetic anisotropy, magnetoelastic, TbFeCo

1. Introduction

The study of magnetic thin films with perpendicular magnetization is particularly important in the magnetic recording and sensors industries. Magnetic anisotropy contributions such as, those related to shape, surface, interface interaction, crystalline structure, and strain determine the conditions required for perpendicular magnetization. R-Fe (R=rare earth) based alloys offer the possibility of developing large magnetostrictions at room temperature. When R-Fe compounds are in form of a thin film then amorphous thin films of these alloys generally exhibit extremely high magnetic anisotropies with easy axis perpendicular to the plane of the film [1-3].

The magnetic anisotropy in TbFeCo originates from interaction between the local electric field and the $4f$ cloud of Tb atoms, and its magnitude reflects the asphericity of the Tb atomic environment. The $4f$ electronic cloud of Tb has an oblate ellipsoid shape with a magnetic moment perpendicular to the equatorial plane. When the easy axis of the magnetic moment is perpendicular to the film plane, the minimum electrostatic energy of $4f$ the cloud occurs when its equatorial plane lies in the plane of the film. Such a configuration should have a minimum

energy as a result of angular dependence of the distance to the different nearest neighbors as well as any non-uniform charge distribution in the equidistant nearest-neighbor shell. This aspherical distribution of electric charge, which is the only fundamental physical phenomenon that can be inferred from macroscopic magnetic measurements, has been expressed in terms of different local anisotropies [2].

In the case of R-Fe₂ alloys, the existing phase compounds are TbFe₂ (terfenol) and TbDyFe₂ (terfenol-D), which exhibit giant positive magnetostriction [4-6]. The R-FeCo has also been investigated in the context of magnetostriction in amorphous alloys of $\text{Tb}(\text{Fe}_{0.55}\text{Co}_{0.45})_{1.5}$ (TerfecoHan), and the TerfecoHan magnetostriction observed was much larger than that observed in other amorphous films of either TbFe or TbCo [7-9].

In the present study, we examined factors influenced by working pressure, such as, the magnetic anisotropy of $\text{Tb}(\text{Fe}_{0.55}\text{Co}_{0.45})_{1.5}$, and we optimized the working pressure conditions required perpendicular magnetic anisotropy.

2. Experiment

Several series of thin films of composition $\text{Tb}(\text{Fe}_{0.55}\text{Co}_{0.45})_{1.5}$ were deposited on Si wafers by dc-magnetron sputtering at a base pressure of 2×10^{-7} Torr and at Ar working pressures in the range 1-7 mTorr. Film thick-

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nesses were 200 nm, which were obtained by controlling sputtering time. During the deposition, a magnetic field of 250 Oe was applied perpendicular film planes to set the unidirectional exchange anisotropy in this direction. All depositions were performed at room temperature.

The magnetic properties of the thin films formed were measured using a Lake shore 7400 series Vibrating Sample Magnetometer (VSM) with the magnetic field applied in-plane and perpendicular to the film plane. Anisotropy fields and coercivity were determined from hysteresis loops. Microstructures were determined by X-ray diffraction using Cu-K α radiation. Elemental compositions were determined by EDX (Energy Dispersive X-ray analysis).

3. Results and Discussion

Fig. 1 shows the X-ray diffraction patterns of Tb(Fe_{0.55}Co_{0.45})_{1.5} deposited from 1 to 7 mTorr and demonstrates the formation of an amorphous film [8]. EDX was also used to determine elemental compositions of Tb(Fe_{0.55}Co_{0.45})_{1.5} films.

The magnetization curves of these films are shown in Fig. 2, which shows magnetization curves versus internal field $H_{int} = H_{ext} - NM$, where H_{ext} , N and M are external field, demagnetization factor and magnetization, respectively. The demagnetization factor of a thin film is given by $N=N_{//}=0$ in-plane and the experimentally determined demagnetization factor in the perpendicular direction is given by $N=N_{\perp}$. The value of N_{\perp} was chosen to correspond to the steepest part of the magnetization curve. The resulting effective values of N_{\perp} were 1, 0.9, 0.7 and 0.5 for deposited films at working pressures of 1, 3, 5, and 7 mTorr, respectively. As compared with the $N_{\perp}=1$ expected for an infinite film, obtained value for as-deposited films were too small, which was attributed to the nucleation of

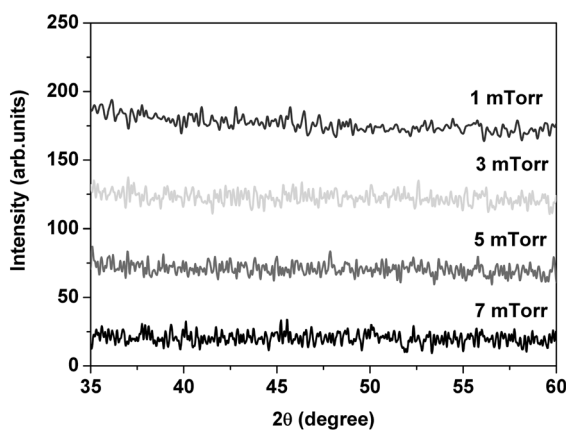


Fig. 1. X-ray diffraction of Tb(Fe_{0.55}Co_{0.45})_{1.5} thin films.

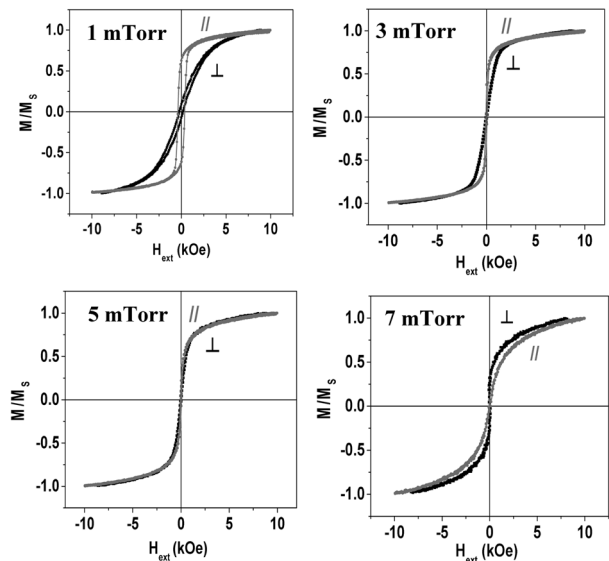


Fig. 2. Hysteresis loops of Tb(Fe_{0.55}Co_{0.45})_{1.5} films with magnetic field applied parallel (//) and perpendicular (⊥) to the plane of the film.

triple domains [8, 10, 11].

Tb(Fe_{0.55}Co_{0.45})_{1.5} films have easy magnetization directions changed from in-plane to the perpendicular to the plane. Anisotropy field can be observed from the hysteresis loops (Fig. 2). Effective anisotropy field can be determined using $H_k = (H_{k//} - H_{k\perp})$, where $H_{k//}$ and $H_{k\perp}$ are the anisotropy fields of in-plane and perpendicular magnetization, respectively [12, 13]. Effective magnetic anisotropy values were calculated using anisotropy field K_u , defined as $\Delta H_k \cdot M_s/2$, where M_s is the magnetization [13].

Fig. 3 provides uniaxial anisotropy values as a function of working pressure. When working pressures were above 5.1 mTorr anisotropies were positive values and perpendicular, and at working pressure is below 5.1 mTorr anisotropies in-plane were negative.

At positive K_u values (perpendicular anisotropy), materials with magnetoelastic anisotropy compensate for external

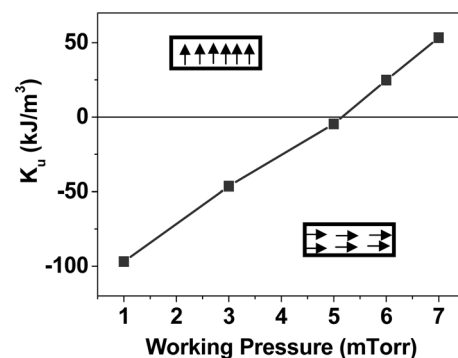


Fig. 3. Dependences uniaxial anisotropy, K_u , on the working pressure of Tb(Fe_{0.55}Co_{0.45})_{1.5} films.

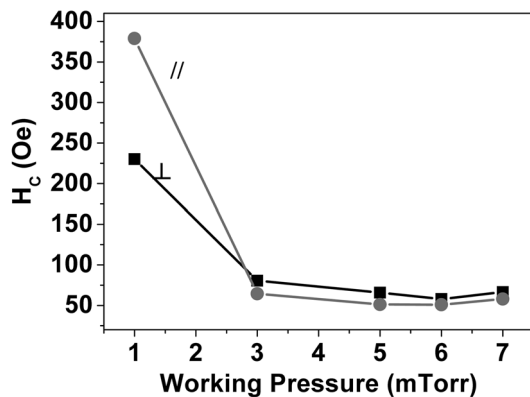


Fig. 4. Coercivity of $\text{Tb}(\text{Fe}_{0.55}\text{Co}_{0.45})_{1.5}$ thin films as function of working pressure with magnetic field applied parallel (//) and perpendicular (\perp) to the plane of the film.

or internal stresses by altering spin rotations. For a film with positive magnetostriction, tensile stress leads to spin orientation in the plane of the film, whereas compressive stress causes spins to orientate perpendicularly along the film plane. Since the thermal expansion coefficients of Tb-FeCo film and the Si substrate result in in-plane anisotropy, it is possible that the observed perpendicular anisotropy is of intrinsic origin, and that it is associated with the structural anisotropy induced during the sputtering process [8]. On the other hand, the perpendicular anisotropy of Tb-FeCo film can also be explained theoretically using the “initial-susceptibility method” by determined magnetostriction value [2]. The relationship between anisotropy and magnetostriction is given by: $\chi = \mu_0 M_s^2 / 2K - 3\lambda_s \sigma$. Here, χ , M_s , K , λ_s , and σ are susceptibility, saturation magnetization, magnetic anisotropy, saturation magnetostriction, and applied tensile stress, respectively [2, 7].

The elimination of the perpendicular anisotropy at low working pressure (below 5.1 mTorr) are isotropic amorphous structure has a lower energy than the as-deposited anisotropic state. Thus, the relaxation of anisotropy without crystallization involves a simple relaxation of the amorphous structure and results in a more stable and homogeneous film structure [8].

Coercivity of $\text{Tb}(\text{Fe}_{0.55}\text{Co}_{0.45})_{1.5}$ films depends on working pressure (Fig. 4) and its coercivity field is lower than that reported in the literature (Ref. 8). Furthermore, its coercivity is strongly affected by internal stress, microstructure, and homogeneity [14].

4. Conclusion

The hysteresis loops obtained using VSM show that

perpendicular anisotropy can be observed in $\text{Tb}(\text{Fe}_{0.55}\text{Co}_{0.45})_{1.5}$ amorphous thin films produced by sputtering at a working pressure > 5.1 mTorr. The effective anisotropies of amorphous thin films were estimated by calculating uniaxial anisotropies.

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